

# Hi-Reliability RAD Capable Optoisolator

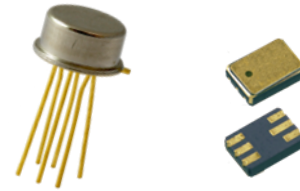


## HCC1000 (Through Hole)

## HCC1001 (SMT)

### Features:

- TID Capable to 100Krad (SI)/cm<sup>2</sup> ELDRS (0.1rad/s)
- Neutron capable to 1E12 neutrons (14MeV)
- Processed to MIL-STD-19500 TXV level
- 1 KV electrical Isolation
- Base Contact provided for conventional transistor biasing

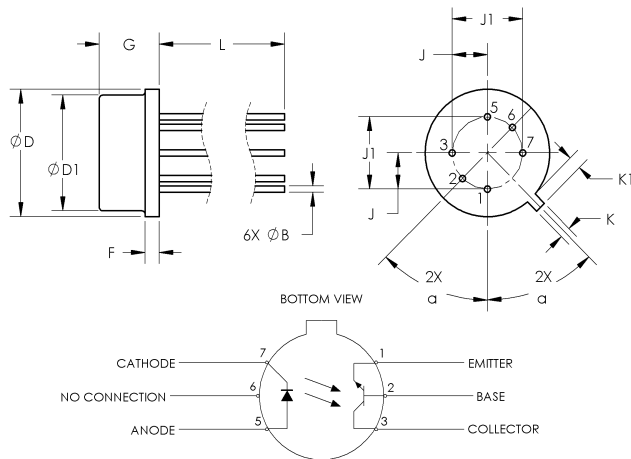


### Description:

These devices are similar to Optek's 4N series of opto isolators with exception of the chips. It is processed per MIL-PRF-19500 TXV level and can be modified per customer SCDs. Each device consists of a IRLED & NPN transistor mounted in either hermetic TO-78 metal can, 6 pin SMD or custom packaging.

### Applications:

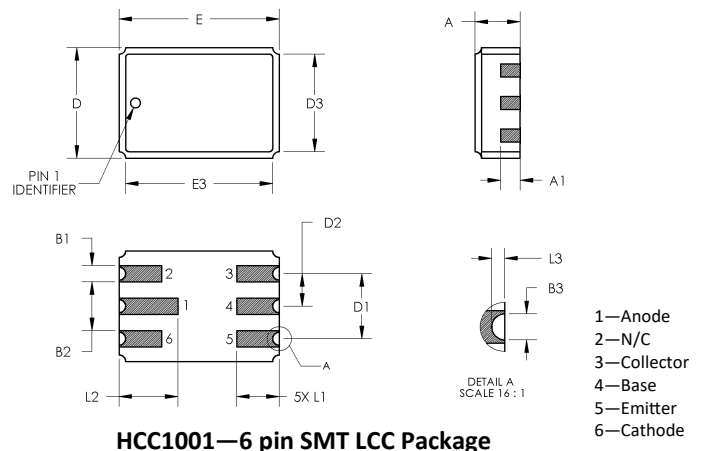
Circuit Electrical Isolation in Space Applications such as Satellites, Launchers, Space Vehicles & Planetary Rovers.



(COLLECTOR MAY OR MAY NOT BE CONNECTED INTERNALLY TO CASE)

**HCC1000—6 leads metal can (TO-78) Package**

LTR	DIMENSIONS			
	INCHES		MILLIMETERS	
$\varnothing D$	MIN	MAX	MIN	MAX
$\varnothing D1$	0.335	0.370	8.51	9.40
$\varnothing B$	0.305	0.335	7.75	8.51
$\alpha$	0.016	0.019	0.41	0.48
F	45° T.P.		45° T.P.	
G	0.155	0.185	3.94	4.70
J	.100 T.P.		2.54 T.P.	
J1	.200 T.P.		5.08 T.P.	
K	0.028	0.034	0.71	0.86
K1	0.029	0.045	0.74	1.14
L	0.500	0.600	12.70	15.24



**HCC1001—6 pin SMT LCC Package**

LTR	DIMENSIONS			
	INCHES		MILLIMETERS	
A	MIN	MAX	MIN	MAX
A	0.066	0.080	1.68	2.03
A1	0.026	0.034	0.66	0.86
B1	0.022	0.028	0.56	0.71
B2	.072 REF		1.83 REF	
B3	0.006	0.022	0.15	0.56
D	0.165	0.175	4.19	4.44
D1	0.095	0.105	2.41	2.67
D2	0.045	0.055	1.14	1.39
D3		0.175		4.44
E	0.240	0.250	6.10	6.35
E3		0.250		6.35
L1	0.060	0.070	1.65	1.78
L2	0.082	0.098	2.08	2.49
L3	0.003		0.08	

### General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

TT Electronics | OPTEK Technology  
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200  
www.ttelectronics.com | sensors@ttelectronics.com

# Hi-Reliability RAD Capable Optoisolator

HCC1000 (Through Hole)

HCC1001 (SMT)



## Electrical Specifications

### Absolute Maximum Ratings ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

Storage Temperature Range	-55 °C to +150 °C
Operating Temperature Range	-55 °C to +150 °C
Input-to-Output Isolation Voltage	$\pm 1.00\text{ kVDC}^{(1)}$
Lead Soldering Temperature (TO-78 Metal Can) [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260 °C <sup>(2)</sup>
Soldering Temperature (SMD) Vapor Phase Reflow for 30 seconds	215 °C

### Input Diode (LED)

Forward DC Current (65 °C or below)	40 mA
Reverse Voltage	2 V
Power Dissipation	60 mW <sup>(3)</sup>

### Output Phototransistor:

Continuous Collector Current	50 mA
Collector-Emitter Voltage	40 V
Collector-Base Voltage	45 V
Emitter-Base Voltage	7.0 V
Power Dissipation	300 mW <sup>(4)</sup>

#### Notes:

1. Measured with input leads shorted together and output leads shorted together.
2. RMA flux is recommended.
3. Derate linearly 1.0 mW/°C above 65 °C.
4. Derate linearly 3.0 mW/°C above 25 °C.

#### General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

TT Electronics | OPTEK Technology  
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200  
www.ttelectronics.com | sensors@ttelectronics.com

# Hi-Reliability RAD Capable Optoisolator

HCC1000 (Through Hole)

HCC1001 (SMT)



## Performance

Electrical Characteristics ( $T_A = 25\text{ °C}$  unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
<b>Input Diode</b>						
$V_F$	Forward Voltage	0.80 1.00 0.70	- - -	1.70 1.9 1.50	V	$I_F = 10.0\text{ mA}$ $I_F = 10.0\text{ mA}, T_A = -55\text{ °C}$ $I_F = 10.0\text{ mA}, T_A = 125\text{ °C}$
$I_R$	Reverse Current	-	-	100	$\mu\text{A}$	$V_R = 2.0\text{ V}$

### Output Phototransistor

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	40	-	-	V	$I_C = 1.0\text{ mA}, I_B = 0, I_F = 0$
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	45	-	-	V	$I_C = 100\text{ }\mu\text{A}, I_B = 0, I_F = 0$
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	7	-	-	V	$I_E = 100\text{ }\mu\text{A}, I_C = 0, I_F = 0$
$I_{C(OFF)}^1$	Collector-Emitter Dark Current	-	-	100	nA	$V_{CE} = 20\text{ V}, I_B = 0, I_F = 0$
$I_{C(OFF)}^2$	Collector-Emitter Dark Current	-	-	100	$\mu\text{A}$	$V_{CE} = 20\text{ V}, I_B = 0, I_F = 0, T_A = 100\text{ °C}$
$I_{CB(OFF)}$	Collector-Base Dark Current	-	-	10	nA	$V_{CB} = 20\text{ V}, I_E = 0, I_F = 0$

### Coupled

$I_{C(ON)}$	On-State Collector Current	1 15 10 15	- - - -	- - - -	mA	$I_F = 1.0\text{ mA}, V_{CE} = 1.0\text{ V}, I_B = 0$ $I_F = 15.0\text{ mA}, V_{CE} = 1.0\text{ V}, I_B = 0$ $I_F = 10.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0$ $I_F = 15.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0$
		2.8 2.0	- -	- -		$I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = -55\text{ °C}$ $I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = 100\text{ °C}$
$I_{CB(ON)}$	On-State Collector Base	30	-	-	$\mu\text{A}$	$V_{CB} = 5\text{ V}, I_E = 0, I_F = 10\text{ mA}$
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage	-	-	0.30	V	$I_F = 20.0\text{ mA}, I_C = 10.0\text{ mA}, I_B = 0$
$H_{FE}$	DC Current Gain	100	-	-	V	$V_{CE} = 5.0\text{ V}, I_C = 10.0\text{ mA}, I_F = 0\text{ mA}$
$R_{IO}$	Resistance (Input-to-Output)	$10^{11}$	-	-	$\Omega$	$V_{I-O} = \pm 1000\text{ VDC}^{(1)}$
$C_{IO}$	Capacitance (Input-to-Output)	-	-	5	pF	$V_{I-O} = 0\text{ V}, f = 1.0\text{ MHz}^{(1)}$
$T_R, T_F$	Rise and Fall Time	-	-	20	$\mu\text{s}$	$V_{CC} = 10.0\text{ V}, I_F = 10.0\text{ mA}, R_L = 100\text{ }\Omega$

Notes:

1. Measured with input leads shorted together and output leads shorted together.

#### General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

TT Electronics | OPTEK Technology  
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200  
www.ttelectronics.com | sensors@ttelectronics.com

# Hi-Reliability RAD Capable Optoisolator

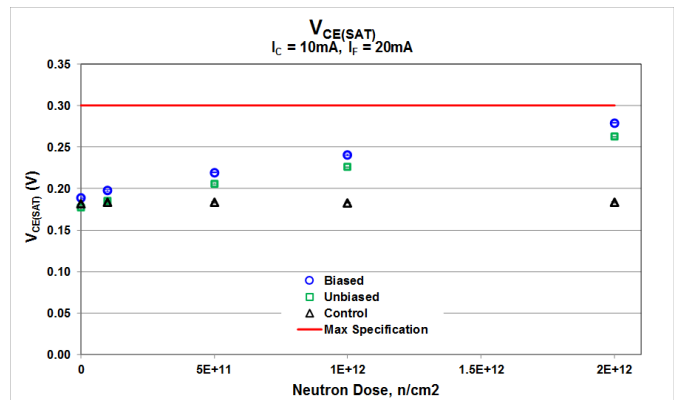
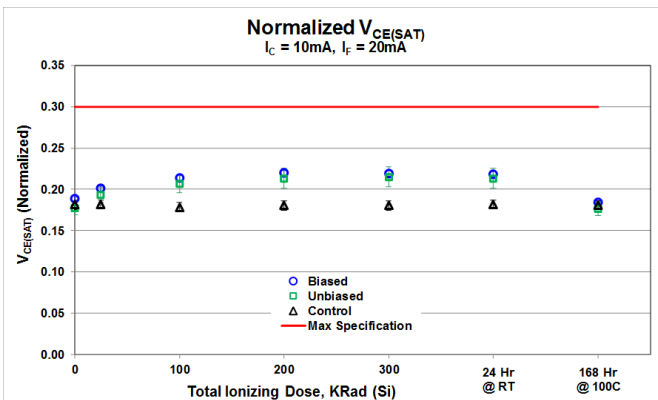
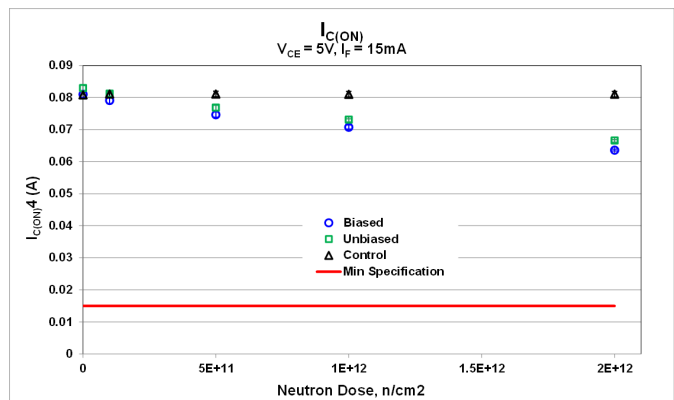
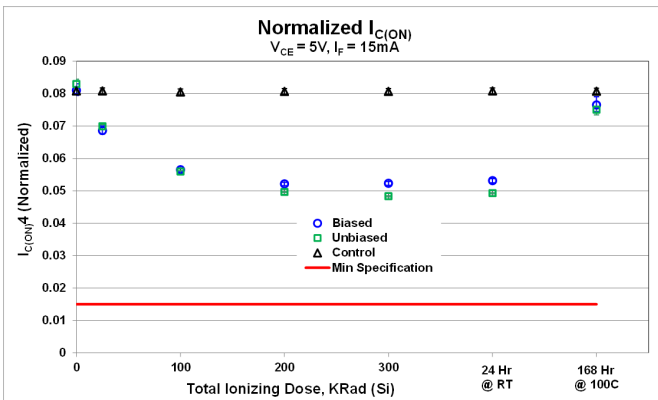
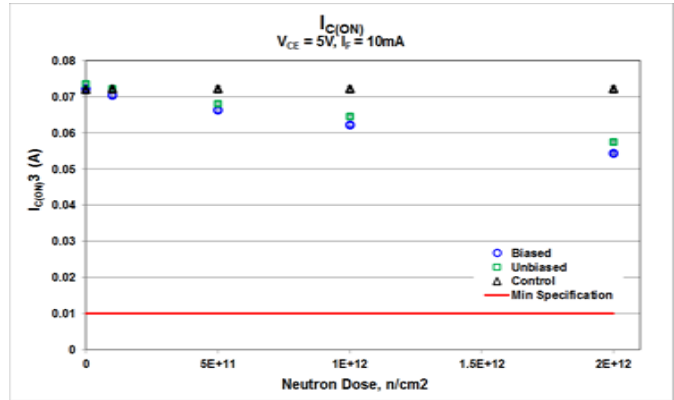
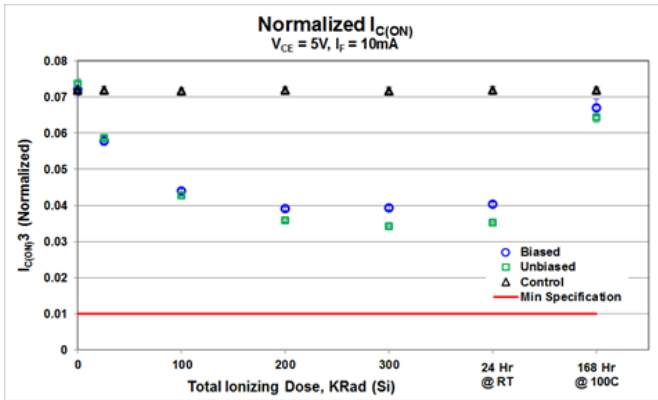


HCC1000 (Through Hole)

HCC1001 (SMT)

## Radiation Test Standards:

- **Total Ionizing Dose:** MIL-STD-883 Method 1019.7 and ASTM F1892-06 ( 0.1rad (si)/s ) dose rate
- **Neutron:** MIL-STD-883 Method 1017.2 and ASTM Designation: E 772—94
- **Full Radiation report available**



### General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

TT Electronics | OPTEK Technology  
 1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200  
[www.ttelectronics.com](http://www.ttelectronics.com) | [sensors@ttelectronics.com](mailto:sensors@ttelectronics.com)

# Hi-Reliability RAD Capable Optoisolator

HCC1000 (Through Hole)

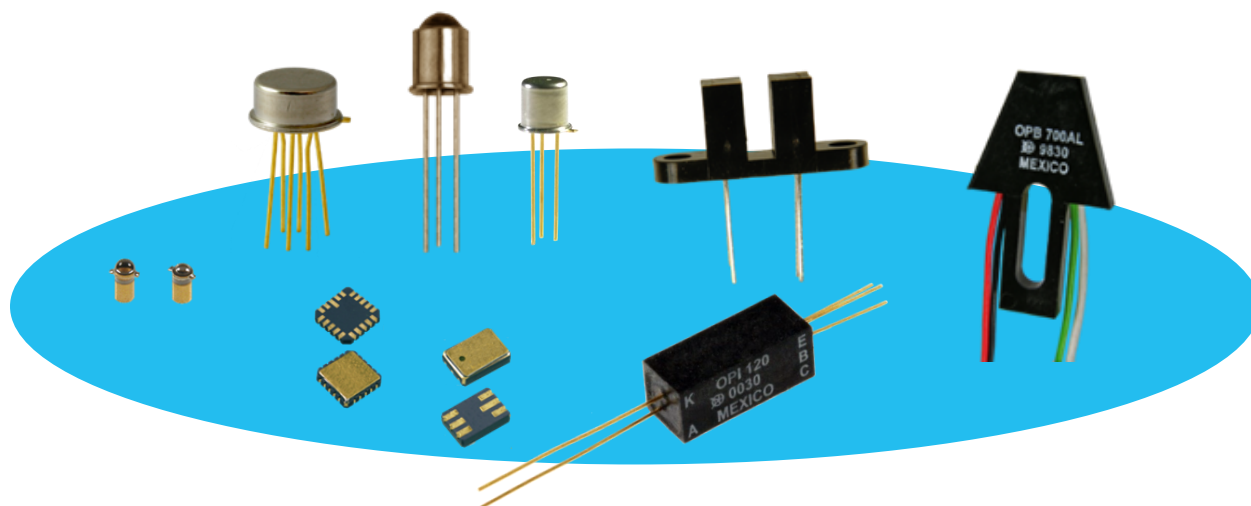
HCC1001 (SMT)



## Packaging

### Package styles available:

Radiation testing was in a TO-78 can; however, functional & radiation samples can be supplied in discrete pairs such as, “pills” or TO-46 / TO-18 metal cans, 4 & 6 pin Hermetic Ceramic LLC, high voltage assemblies like the OPI120 and OPI150 hermetic high voltage isolators and more.



### General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

© TT electronics plc

TT Electronics | OPTEK Technology  
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200  
www.ttelectronics.com | sensors@ttelectronics.com

Rev C 07/2020 Page 5

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [Transistor Output Optocouplers](#) category:*

*Click to view products by [TT Electronics](#) manufacturer:*

Other Similar products are found below :

[LTV-814S-TA](#) [LTV-824HS](#) [66095-001](#) [6N136-X017T](#) [MCT6-X007](#) [MOC8101-X017T](#) [PS2561A-1-W-A](#) [PS2561B-1-L-A](#) [PS2561L-1-V-A](#)  
[MRF658](#) [IL755-1X007](#) [ILD2-X006](#) [ILD74-X001](#) [ILQ615-2X017](#) [ILQ615-3X016](#) [LDA102S](#) [LDA110S](#) [PS2561-1-V-W-A](#) [PS2561AL-1-V-](#)  
[A](#) [PS2561L1-1-L-A](#) [PS2701A-1-F3-P-A](#) [PS2801-1-F3-P-A](#) [PS2911-1-L-AX](#) [CNY17-2X017](#) [CNY17-4X001](#) [CNY17-4X017](#) [CNY17F-](#)  
[1X007](#) [CNY17F-2X017](#) [CNY17F-4X001](#) [CNY17G-1](#) [LTV-214](#) [LTV-702VB](#) [LTV-733S](#) [LTV-816S-TA](#) [LTV-825S](#) [TCET1113](#) [TCET2100](#)  
[4N25-X007T](#) [IL215AT](#) [ILD615-1X007](#) [ILQ2-X007](#) [VOS615A-2T](#) [WPPC-A11066AA](#) [WPPC-A11066AD](#) [WPPC-A11084ASS](#) [WPPC-](#)  
[A21068AA](#) [WPPC-D11066AA](#) [WPPC-D21068ED](#) [WPPC-D410616EA](#) [WPPC-D410616ED](#)